





Features:

- RoHS Compliant
- 250 Watts
- DC 3.0GHz
- AIN Ceramic
- Non-Nichrome Resistive Element
- Low VSWR
- 100% Tested

Description:

The E250N50X4B is high performance Aluminum Nitride (AIN) termination intended as a cost competitive alternative to Beryllium Oxide (BeO). The termination is well suited to all cellular frequency bands such as; AMPS, GSM, DCS, PCS, PHS and UMTS. The high power handling makes the part ideal for terminating circulators and for use in power combiners. The termination is also RoHS compliant!

General Specifications:

Resistive Element	Thick film
Substrate	AIN Ceramic
Terminal Finish	Matte Tin over Nickel Barrier
Operating Temperature	-50 to +200°C (see de rating chart)

Electrical Specifications:

Resistance Value: 50 Ohms Nominal

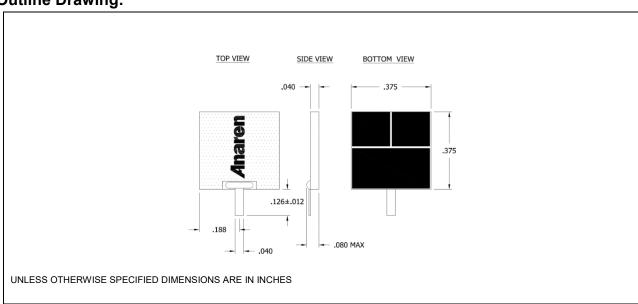
 Power:
 250 Watts

 Frequency Range:
 DC - 3.0 GHz

 Return Loss
 > 20 dB

Specification based on unit properly installed using suggested mounting instructions and a 50 ohm nominal impedance. **Specifications subject to change.**

Outline Drawing:

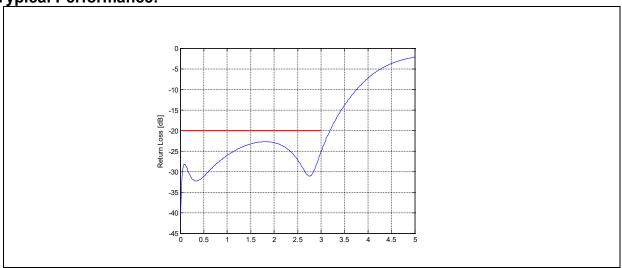


Tolerance is ± 0.010 ", unless otherwise specified. Designed to meet or exceed applicable portions of MIL-E-5400. **All dimensions in inches.**

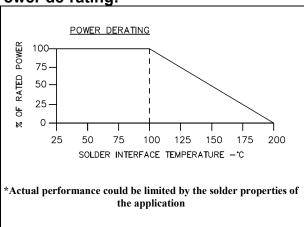




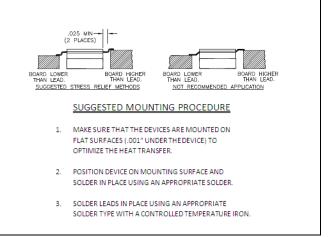




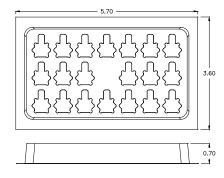
Power de-rating:



Mounting Footprint:



Packaging Information (Tray and Cover):



UNLESS OTHERWISE SPECIFIED DIMENSIONS ARE IN INCHES

Contact us:

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